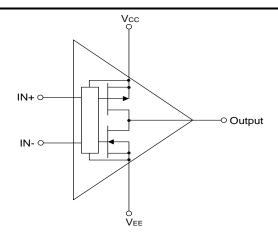


# **Pin Descriptions**

AZV3001	AZV3001				
Pin Name	Pin Number	Function			
V <sub>CC</sub>	6	Supply Voltage			
V <sub>EE</sub>	2	Supply Voltage			
IN+	3	Non-Inverting Input			
IN-	4	Inverting Input			
OUT	1	Comparator Output			
N.C.	5	No Connection			

AZV3002	V3002				
Din Nama	Pin Numb		Formation		
Pin Name	U-FLGA1616-8	SO-8	Function		
Vcc	8	8	Supply Voltage		
$V_{EE}$	4	4	Supply Voltage		
IN1+	3	3	Non-Inverting Input of Comparator 1		
IN1-	2	2	Inverting Input of Comparator 1		
OUT1	1	1	Comparator 1 Output		
IN2+	5	5	Non-Inverting Input of Comparator 2		
IN2-	6	6	Inverting Input of Comparator 2		
OUT2	7	7	Comparator 2 Output		

# **Functional Block Diagram**



# **Absolute Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Р	Parameter			Unit
V <sub>CC</sub>	Supply Voltage		-	6	V
VI	Input Voltage		-0.3	V <sub>CC</sub> +0.3	V
t <sub>SC(O)</sub>	Output Short-Circuit Time		-	Indefinite	S
T <sub>j(max)</sub>	Maximum Junction Tempe	Maximum Junction Temperature		+150	°C
T <sub>STG</sub>	Storage Temperature	Storage Temperature		+150	°C
		X2-DFN1410-6	315		
$\theta_{JA}$	Thermal Resistance (Junction-to-Ambient)	U-FLGA1616-8	3	06	°C/W
	(0.000000000000000000000000000000000000	SO-8	2	20	
		X2-DFN1410-6	1	50	
θ <sub>JC</sub> Thermal Resistance (Junction-to-Case)	U-FLGA1616-8	1	122		
	(Garionelli to Gase)	SO-8	8	30	1



# DC Electrical Characteristics (V<sub>CC</sub>=1.6V to 5.5V, V<sub>EE</sub>=0V; V<sub>CM</sub>=0.5V<sub>CC</sub> unless otherwise specified.)

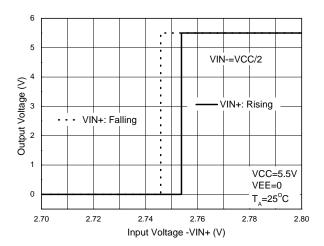
				+25°C		-40°C t	o +85°C	
Symbol	Parameter	Conditions	Min	Тур	Max	Min	Max	Units
V. n.co=	Hysteresis Voltage	-	6	9	13	-	-	mV
V <sub>HYST</sub>	Trysteresis Voltage	V <sub>CC</sub> =1.3V		20	-	-	-	mV
V <sub>I(offset)</sub>	Offset Input Voltage	-	-30	0.5	+30	-30	+30	mV
v I(offset)	Onset input voltage	V <sub>CC</sub> =1.3V	-	3	-	-	-	mV
		$I_O = -0.5$ mA; $V_{CC} = 1.3$ V	İ	1.24	•	-	-	>
\	High-Level Output Voltage	$I_O = -0.5$ mA; $V_{CC} = 1.6$ V	-	1.55	-	1.35	-	V
Vон	High-Level Output voltage	$I_O = -3mA$ ; $V_{CC} = 3.0V$	-	2.85	-	2.7	-	V
		$I_O = -5mA$ ; $V_{CC} = 5.5V$	-	5.33	-	5.2	-	V
	Low-Level Output Voltage	$I_O = -0.5$ mA; $V_{CC} = 1.3$ V	-	0.05	-	-	-	V
.,		$I_O = -0.5$ mA; $V_{CC} = 1.6$ V	-	0.04	-	-	0.25	V
$V_{OL}$		$I_{O} = -3mA$ ; $V_{CC} = 3.0V$	-	0.14	-	-	0.3	V
		$I_{O} = -5mA$ ; $V_{CC} = 5.5V$	-	0.2	-	-	0.3	V
V <sub>CM</sub>	Common-Mode Voltage	V <sub>CC</sub> = 1.3V to 5.5V	-	V <sub>EE</sub> to	-	-	-	V
los	Output Short-Circuit Current	$V_{CC} = 5.5V;$ $V_O = V_{EE}$ or $V_{CC}$	-	68	-	-	-	mA
CMRR	Common-Mode Rejection Ratio	ΔV <sub>CM</sub> = V <sub>CC</sub>	-	70	-	-	-	dB
PSRR	Power Supply Rejection Ratio	ΔV <sub>CC</sub> = 1.95V	45	80	-	-	-	dB
I <sub>IB</sub>	Input Bias Current	-	-	1	-	-	-	pA
	Supply Current – AZV3001	-	-	6	-	-	9	μA
Icc	Supply Current – AZV3002	-	-	9			12	μA

# AC Electrical Characteristics (V<sub>CC</sub>=1.6V to 5.5V, V<sub>EE</sub>=0V; V<sub>CM</sub>=0.5V<sub>CC</sub> unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t <sub>pd</sub>	Propagation Delay	20mV Overdrive; C <sub>L</sub> =15pF		0.8		μs
t <sub>THL</sub>	High to Low Output Transition Time	V <sub>CC</sub> =5.5V; C <sub>L</sub> -50pF		10		ns
t <sub>TLH</sub>	Low to High Output Transition Time	$V_{CC}$ =5.5V; $C_L$ =50pF	_	10	_	ns



## **Performance Characteristics**



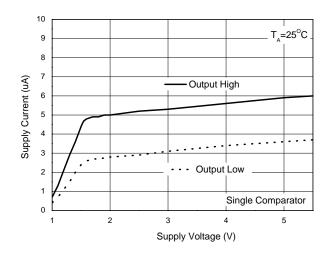


Figure 1 Input Hysteresis Voltage

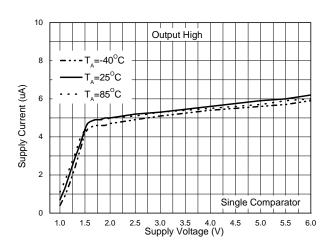


Figure 2 Supply Current vs. Supply Voltage

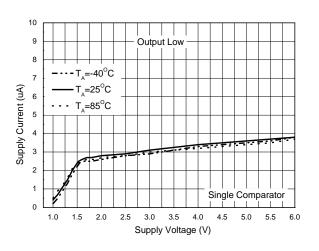
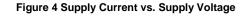
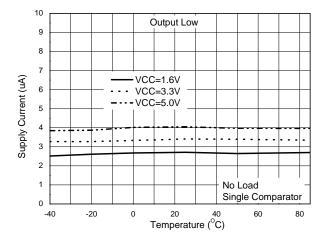


Figure 3 Supply Current vs. Supply Voltage





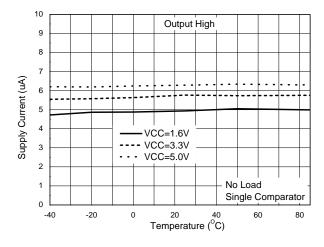
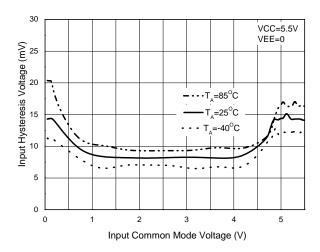


Figure 5 Supply Current vs. Temperature

Figure 6 Supply Current vs. Temperature



## Performance Characteristics (continued)



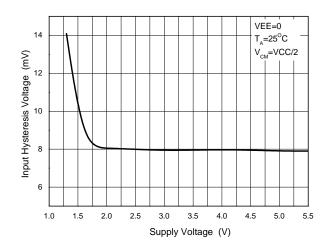


Figure 7 Input Hysteresis Voltage

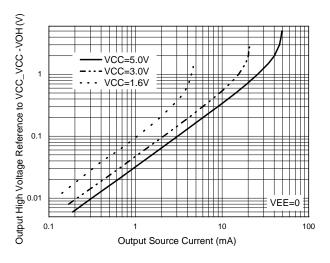


Figure 8 Input Hysteresis Voltage

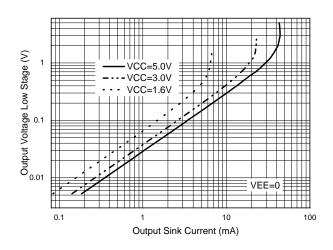
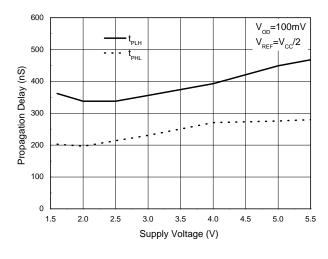


Figure 9 Output Voltage vs. Output Source Current





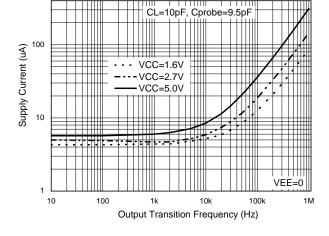


Figure 11 Propagation Delay vs. Supply Voltage

Figure 12 Supply Current vs. Transition Frequency



# **Application Information**

#### Description

The AZV3001/2 are single and dual low-voltage, low-power comparators. These devices are designed for rail-to-rail input and output applications. The AZV3001 device consumes only 6µA supply current while achieving a typical propagation delay 0.8µS under 20mV input overdrive condition. These family comparators are guaranteed to operate at a low supply voltage range of 1.6V to 5.5V.

The AZV3001 /2 series has a typical internal hysteresis of 9.0mV. This allows for greater noise immunity and clean output switching.

#### The Output Stage

The AZV3001 and AZV3002 feature a push-pull output, which have a complementary P- and N-Channel output stage. When the output switches, there is a direct patch between  $V_{CC}$  and  $V_{EE}$ , causing increased output sinking or sourcing current during the transition. Following the transition, the output current decreases and supply current returns to  $6\mu$ A, thus maintaining low power consumption.

Many comparators consume more current during switching than during steady-state operation. However, with this family of comparators, the supply current change during an output transition is extremely small. The graph of Supply Current vs. Output Transition Frequency shows the minimal supply current increase as the output switching frequency approaches 1KHz. In battery- powered applications, this characteristic results in a substantial increase in battery life.

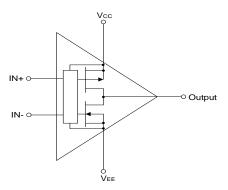


Figure 13 AZV3001/2 Complementary Output Configuration

#### Internal Input Hysteresis Voltage (VHYST)

Many comparators oscillate in the linear region of operation because of noise or undesired parasitic feedback. This tends to occur when the voltage on one input is equal to, or very close to the voltage on the other input. The AZV3001/2 have internal 9mV (Typ.) hysteresis to counter parasitic effects and noise.

The hysteresis in a comparator creates two trip points: one for the rising input voltage ( $V_{HYST+}$ ) and one for the falling input voltage ( $V_{HYST-}$ ). The difference between the trip points is the hysteresis ( $V_{HYST}$ ). When the comparator's input voltages are equal, the hysteresis effectively causes one comparator input to move quickly past the other, thus taking the input out of the region where oscillation occurs. Figure 1 illustrates the case in which  $V_{IN-}$  has a fixed voltage applied, and  $V_{IN+}$  is varied. If the inputs were reversed, the figure would be the same, except with an inverted output.

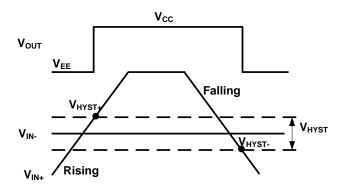


Figure 14 AZV3001 / 2 Internal Input Hysteresis Voltage



# **Application Information (continued)**

#### **External Hysteresis Application**

The AZV3001 and AZV3002 have a hysteresis transfer curve that is a function of the following three components:

V<sub>TH</sub>: the actual set voltage or threshold trip voltage

V<sub>OS</sub>: the internal offset voltage between VIN+ and VIN-. This voltage is added to VTH to form the actual trip point at which the comparator must respond in order to change output states.

V<sub>HYST</sub>: internal hysteresis (or trip window) that is designed to produce comparator sensitivity to noise.

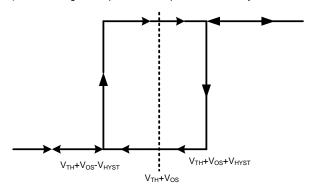


Figure 15 AZV3001 Hysteresis Transfer Curve

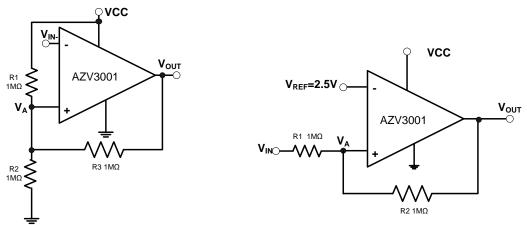


Figure 16. Inverting Comparator With Hysteresis

Figure 17. Non-Inverting Comparator With Hysteresis

#### No Phase Inversion

AZV3001 and AZV3002 are rail-to-rail input comparators, with the input common-mode voltage range reaching to the supply rails for both positive and negative supplies. The AZV3001 and AZV3002 are designed to prevent phase inversion when the input pins exceed the supply voltage. Figure 18 shows the AZV3001/2 response when input voltages exceed the supply, resulting in no phase inversion.

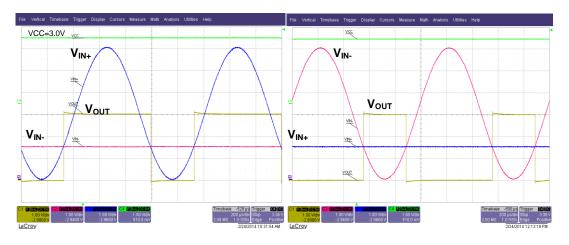
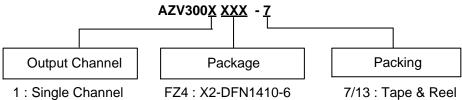


Figure 18 Comparator Response to Input Voltage –No Phase Inversion



## **Ordering Information**



2: Dual Channel

RL: U-FLGA1616-8

S: SOP-8L

		Package		7"/13" Tap	e and Reel
	Part Number	Code	Packaging	Quantity	Part Number Suffix
<b>Po</b> ,	AZV3001FZ4-7	FZ4	X2-DFN1410-6	5,000/Tape & Reel	-7
	AZV3002RL-7	RL	U-FLGA1616-8	3,000/Tape & Reel	-7
Pb,	AZV3002S-13	S	SO-8	2500/Tape & Reel	-13

Note: 4. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

## Marking Information

(1) X2-X2-DFN1410-6

(Top View)

<u>XX</u> <u>Y W X</u> XX: Identification Code

Y: Year: 0~9

 $\overline{\underline{W}}$ : Week: A~Z: 1~26 week;

a~z: 27~52 week; z represents

52 and 53 week X: Internal Code

Part Number	Package	Identification Code
AZV3001FZ4	X2-DFN1410-6	YA

(2) U-FLGA1616-8

(Top View)

XX<u>Y W X</u> XX: Identification Code

Y: Year: 0~9

W: Week: A~Z: 1~26 week;

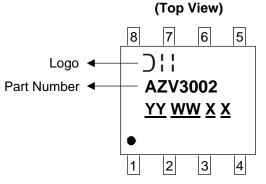
a~z: 27~52 week; z represents

52 and 53 week

<u>X</u>	:	Intern	ıaı	Coc	e

Part Number	Package	Identification Code
AZV3002RL	U-FLGA1616-8	XD

(3) SO-8



YY: Year: 14,15,16~

WW: Week: 01~52; 52

represents 52 and 53 week

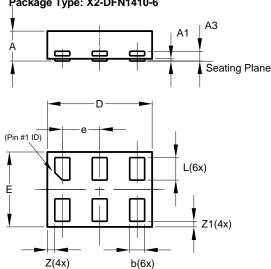
XX: Internal Code



## Package Outline Dimensions (All dimensions in mm.)

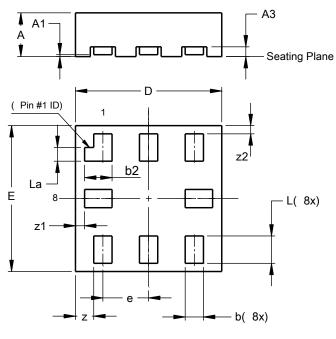
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

### (1) Package Type: X2-DFN1410-6



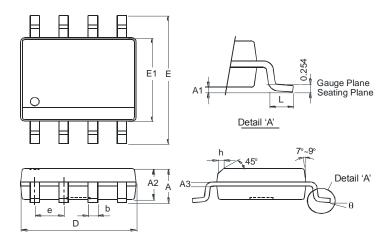
	X2-DFN1410-6					
Dim	Min	Max	Тур			
Α	_	0.40	0.39			
A1	0.00	0.05	0.02			
A3			0.13			
b	0.15	0.25	0.20			
D	1.35	1.45	1.40			
Е	0.95	1.05	1.00			
е			0.50			
L	0.25	0.35	0.30			
Z			0.10			
<b>Z</b> 1	0.045	0.105	0.075			
All [	Dimensi	ions in i	mm			

## (2) U-FLGA1616-8



	U-FLGA1616-8					
Dim	Min	Max	Тур			
Α	0.45	0.55	0.50			
A1	0.00	0.05	0.02			
А3	-	-	0.176			
b	0.15	0.25	0.20			
b2	-	-	0.30			
D	1.55	1.65	1.60			
Е	1.55	1.65	1.60			
е		0.50BS0				
L	0.25	0.35	0.30			
La	-	-	0.15			
Z	-	-	0.20			
z1	-	-	0.10			
z2	-	-	0.09			
Α	II Dimer	nsions in	mm			

# (3) SO-8



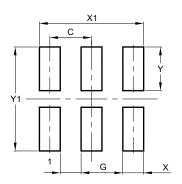
	SO-8				
Dim	Min	Max			
Α	ı	1.75			
A1	0.10	0.20			
A2	1.30	1.50			
A3	0.15	0.25			
b	0.3	0.5			
D	4.85	4.95			
Е	5.90	6.10			
E1	3.85	3.95			
е	1.27	Тур			
h	-	0.35			
L	0.62	0.82			
θ	0°	8°			
All Di	mension	s in mm			



# **Suggested Pad Layout**

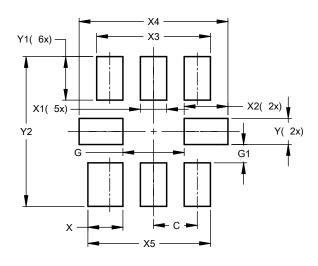
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

## (1) Package Type: X2-DFN1410-6



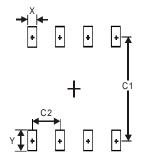
Dimensions	Value (in mm)
С	0.500
G	0.250
Х	0.250
X1	1.250
Y	0.525
Y1	1.250

## (2)U-FLGA1616-8



Dimensions	Value (in mm)
С	0.500
G	0.700
G1	0.210
X	0.400
X1	0.300
X2	0.500
Х3	1.300
X4	1.700
X5	1.400
Y	0.300
Y1	0.500
Y2	1.720

# **(3)SO-8**



Dimensions	Value (in mm)
Х	0.60
Y	1.55
C1	5.4
C2	1.27



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